

# ESD Protection Diodes with Ultra-Low Capacitance

The FTV05BLDFN0603 is designed to protect voltage sensitive components that require ultra—low capacitance from ESD and transient voltage events. Excellent clamping capability, low capacitance, low leakage, and fast response time, make these parts ideal for ESD protection on designs where board space is at a premium. Because of its low capacitance, it is suited for use in high frequency designs such as USB 2.0 high speed and antenna line applications.

### **Specification Features:**

- Ultra Low Capacitance 3pF
- Low Clamping Voltage
- Small Body Outline Dimensions:

(0.61 mm x 0.31 mm)

- Low Body Height: 0.28 mm
- Stand-off Voltage: 5 V
- Low Leakage
- $\bullet$  Response Time is Typically < 1.0 ns
- IEC61000-4-2 Level 4 ESD Protection
- This is a Pb- Free Device





DFN0603-D



C = Specific Device Code
M = Month Code

#### Mechanical Characteristics:

CASE: Void-free, transfer-molded, thermosetting plastic

Epoxy Meets UL 94V- 0

LEAD FINISH: 100% Matte Sn (Tin)

#### **Ordering information**

Device	Marking	Shipping
FTV05BLDFN0603	С	15000/Tape&Reel

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit	
IEC 61000-4-2 (ESD) Contact Air		± <b>10</b> ±15	kV	
Total Power Dissipation on FR-5 Board (Note 1) @ Ta = 25℃	P <sub>D</sub>	200	mW	
Storage Temperature Range	T <sub>stg</sub>	-55 to +15 <b>0</b>	°C	
Junction Temperature Range	$T_J$	-55 to +15 <b>0</b>	°C	
Lead Solder <b>Temperature</b> — <b>Maximum</b> (10 Second Duration)	TL	260	°C	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1.  $FR-5 = 1.0 \times 0.75 \times 0.62$  in.

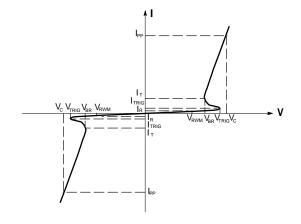




## **ELECTRICAL CHARACTERISTICS**

(TA = 25°C unless otherwise noted)

Symbol	Parameter					
I <sub>PP</sub>	Maximum Reverse Peak Pulse Current					
V <sub>C</sub>	Clamping Voltage @ IPP					
$V_{RWM}$	Reverse standeff voltage					
I <sub>R</sub>	Maximum Reverse Leakage Current @ VRWM					
$V_{BR}$	Breakdown Voltage @ IT					
I <sub>T</sub>	Test Current					
$V_{TRIG}$	Reverse trigger voltage					
I <sub>TRIG</sub>	Reverse trigger current					



Bi-Directional TVS

#### **ELECTRICAL CHARACTERISTICS** (TA = 25 ℃ unless otherwise noted)

		V <sub>RWM</sub> (V)	I <sub>R</sub> (nA) @ V <sub>RWM</sub>	V <sub>BR</sub> (V) @ IT =1mA (Note 2)	C (	pF)	V <sub>C</sub> (V) @ I <sub>PP</sub> = 3.5A (Note 3)	I <sub>PP</sub> (A) t <sub>p</sub> =8/20μs	P <sub>PP</sub> (W)	v <sub>c</sub>
Device	Device Marking	Max	Max	Min	Тур	Max	Max	Max	Max	Per IEC61000-4-2 (Note4)
FTV05BLDFN0603	С	5.0	100	5.5	2.7	3.5	11.5	3.5	40	Figures 1 and 2 See Below

- VBR is measured with a pulse test current IT at an ambient temperature of 25°C.
- Surge current waveform per Figure 4.
   For test procedure see Figures 3.

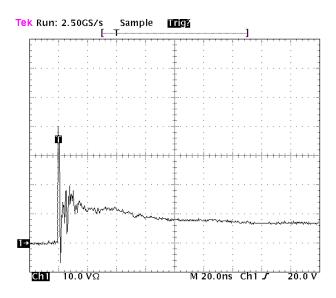


Figure 1. ESD Clamping Voltage Screenshot Positive 8 kV Contact per IEC61000-4-2

Revision No: 0

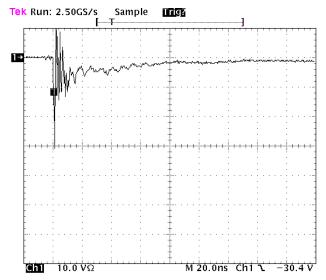


Figure 2. ESD Clamping Voltage Screenshot Negative 8 kV Contact per IEC61000-4-2



## FTV05BLDFN0603

IEC 61000-4-2 Spec.

	<u>_</u>			
Level	Test Voltage (kV)	First Peak Current (A)	Current at 30 ns (A)	Current at 60 ns (A)
1	2	7.5	4	2
2	4 15		8	4
3	6	22.5	12	6
4	8	30	16	8

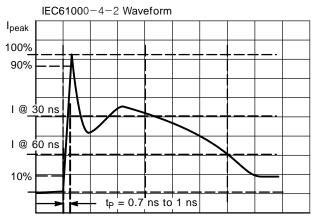


Figure 3. IEC61000-4-2 Spec

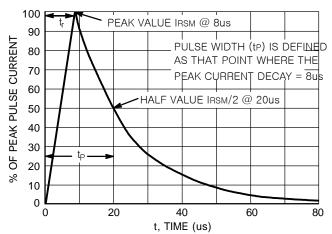
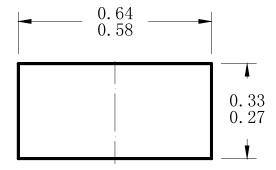


Figure 4. 8 X 20 us Pulse Waveform

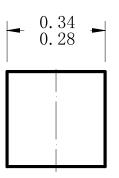


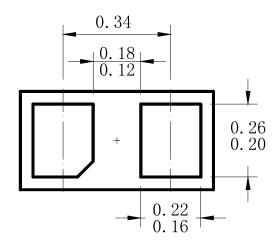
# DFN0603-D

### **DIMENSION OUTLINE:**









# Soldering Footprint

